



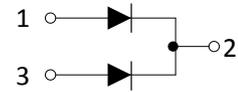
Features

- High Junction Temperature Capability
- Low Leakage Current
- Dual Diode Construction—Terminals 1 and 3 Must be Connected for Parallel Operation at Full Rating

Maximum Ratings (PER LEG)

| Rating | Symbol | Value | Unit |
|---|-----------|----------------|-------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | 100 | Volts |
| Working Peak Reverse Voltage | V_{RWM} | | |
| DC Blocking Voltage | V_R | | |
| Average Rectified Forward Current Per Leg (Rate V_R) $T_C=125^{\circ}C$ Per Package | $I_F(AV)$ | 10 20 | Amps |
| Nonrepetitive Peak Surge Current (8.3ms, half sine wave) | I_{FSM} | 150 | Amps |
| Peak Repetitive Reverse Surge Current (2.0 μ s, 1.0kHz) | I_{RRM} | 2.5 | Amps |
| Operating Junction Temperature | T_J | -65 to +175 | $^{\circ}C$ |
| Storage Temperature | T_{stg} | -65 to +175 | $^{\circ}C$ |

**20Amp High Voltage
Supper Junction
Power Rectifier
100Volts**



ITO-220AB
CASE 221D

Thermal Parameters

| Symbol | Parameter | | | Value | Unit |
|---------------|------------------|------------|-----------|-------|---------------|
| $R_{th(j-c)}$ | Junction to case | TO-220FPAB | Per diode | 4.5 | $^{\circ}C/W$ |
| | | | Total | 3.8 | |
| $R_{th(c)}$ | Coupling | TO-220FPAB | Total | 2.9 | |

When the diodes 1 and 2 are used simultaneously: $T_j(\text{diodes } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{per diode}) + P(\text{diode } 2) \times R_{th(c)}$

Static Electrical Characteristics (per diode)

| Symbol | Test conditions | | | Min_ | Typ_ | Max_ | Unit |
|---------|-------------------------|----------------------|-----------------|------|------|------|------|
| I_R^* | Reverse leakage current | $T_j = 25^{\circ}C$ | $V_R = V_{RRM}$ | - | - | 0.1 | mA |
| | | $T_j = 125^{\circ}C$ | | - | 5 | 10 | |
| V_F^* | Forward voltage drop | $T_j = 25^{\circ}C$ | $I_F = 10A$ | - | - | 0.76 | V |
| | | $T_j = 125^{\circ}C$ | | - | 0.65 | 0.69 | |
| | | $T_j = 25^{\circ}C$ | $I_F = 20A$ | - | - | 0.86 | |
| | | $T_j = 125^{\circ}C$ | | - | 0.68 | 0.73 | |

*Pulse Test: Pulse Width = 380 μ s, Duty Cycle \leq 2.0%

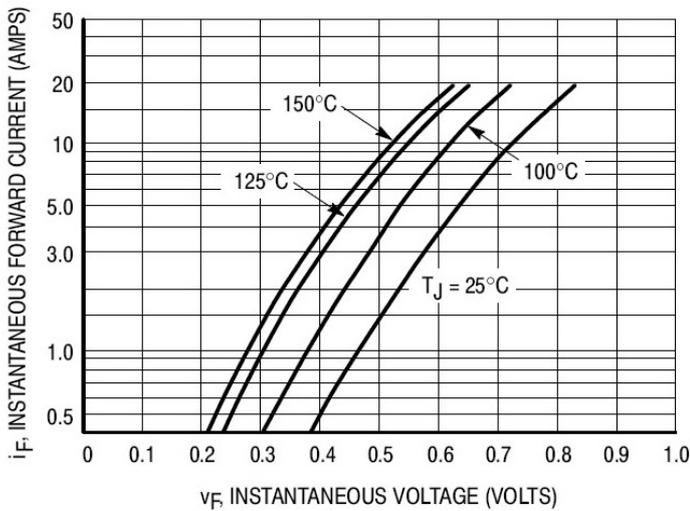


Figure 1. Typical Forward Voltage Per Diode

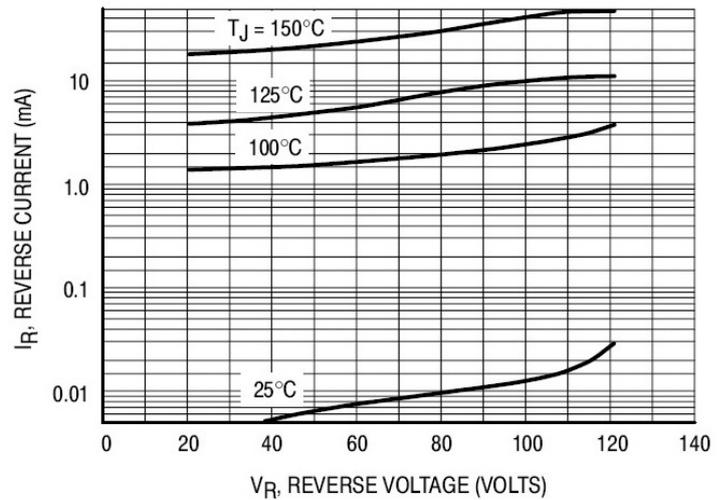


Figure 2. Typical Reverse Current Per Diode

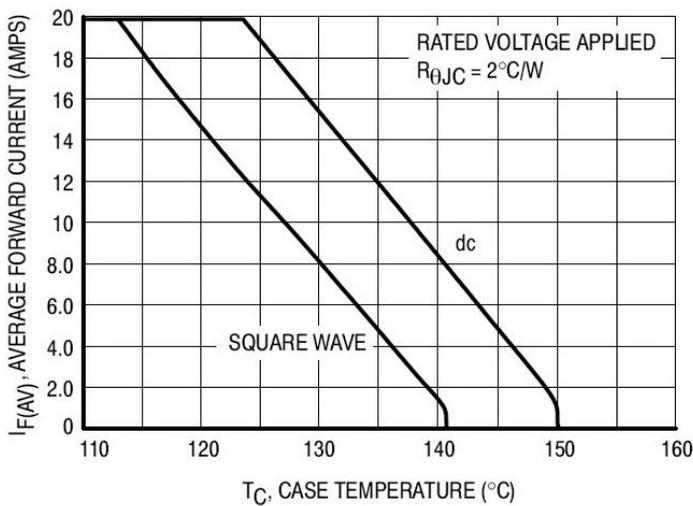


Figure 3. Current Derating, Case

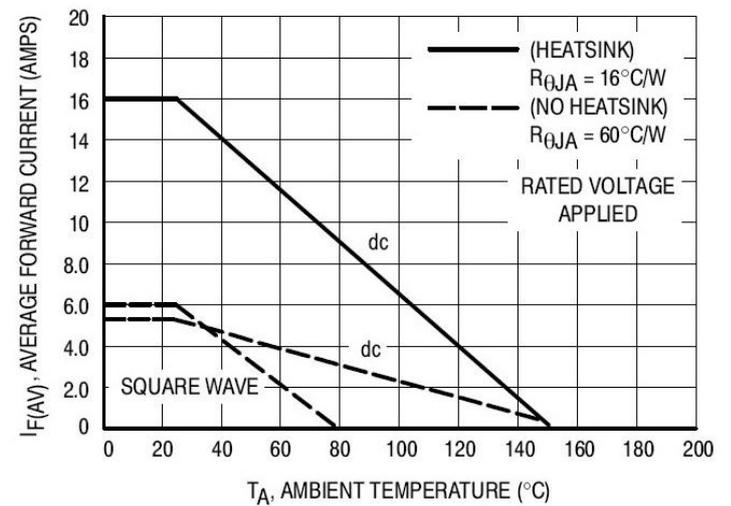


Figure 4. Current Derating, Ambient

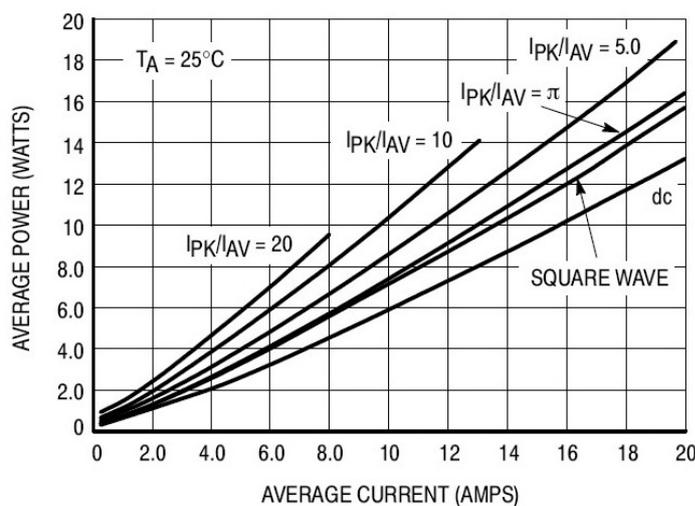
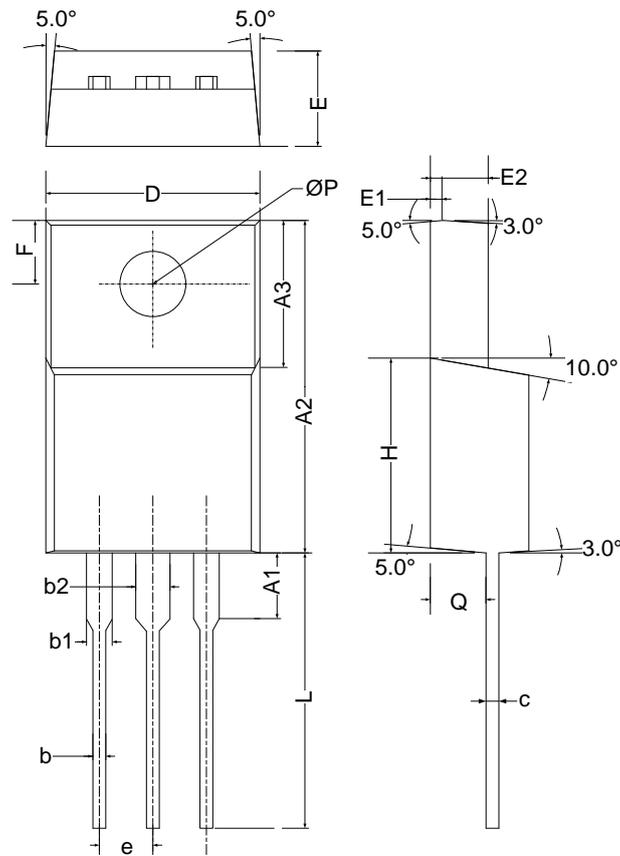


Figure 5. Average Power Dissipation and Average Current



| Ref. | Dimensions (mm) | | |
|------|-----------------|------|-------|
| | MIN | TYPE | MAX |
| A1 | 2.8 | 3.3 | 3.9 |
| A2 | 14.7 | 15.3 | 15.65 |
| A3 | 6.28 | 6.7 | 6.9 |
| b | 0.55 | 0.65 | 0.75 |
| b1 | 0.99 | 1.20 | 1.30 |
| b2 | 1.06 | 1.60 | 1.75 |
| c | 0.5 | 0.6 | 0.7 |
| D | 9.7 | 10.0 | 10.3 |
| E | 4.3 | 4.5 | 4.7 |
| E1 | 0.5 | 0.6 | 0.9 |
| E2 | 2.5 | 2.7 | 2.9 |
| F | 2.81 | 3.0 | 3.35 |
| H | 7.9 | 8.6 | 9.2 |
| L | 12.5 | 13.0 | 13.6 |
| P | 2.8 | 3.0 | 3.4 |
| Q | 2.4 | 2.6 | 2.8 |